

CMOS Digital Integrated Circuits Silicon Monolithic

# TC74VCX125FK

#### 1. Functional Description

· Low-Voltage Quad Bus Buffer with 3.6-V Tolerant Inputs and Outputs

#### 2. General

The TC74VCX125FK is a high-performance CMOS quad bus buffer which is guaranteed to operate from 1.2~V to 3.6~V. Designed for use in 1.5~V, 1.8~V, 2.5~V or 3.3~V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

This device requires the 3-state control input  $\overline{OE}$  to be set high to place the output into the high impedance state. All inputs are equipped with protection circuits against static discharge.

#### 3. Features

- (1) Low-voltage operation:  $V_{CC} = 1.2 \text{ to } 3.6 \text{ V}$
- (2) High-speed operation:  $t_{pd} = 2.8 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

$$t_{pd} = 3.4 \text{ ns (max) (V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$$

$$t_{pd} = 6.8 \text{ ns (max)} (V_{CC} = 1.65 \text{ to } 1.95 \text{ V})$$

$$t_{pd} = 13.6 \text{ ns (max) (V}_{CC} = 1.4 \text{ to } 1.6 \text{ V})$$

$$t_{pd} = 34.0 \text{ ns (max) (V}_{CC} = 1.2 \text{ V)}$$

(3) Output current:  $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$ 

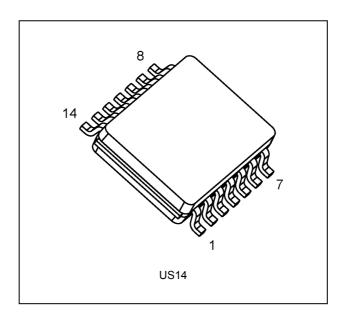
$$I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$$

$$I_{OH}/I_{OL}$$
 = ±6 mA (min) ( $V_{CC}$  = 1.65 V)

$$I_{OH}/I_{OL} = \pm 2$$
 mA (min) ( $V_{CC} = 1.4$  V)

(4) 3.6 V tolerant function and power-down protection provided on all inputs and outputs.

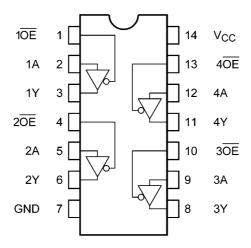
#### 4. Packaging



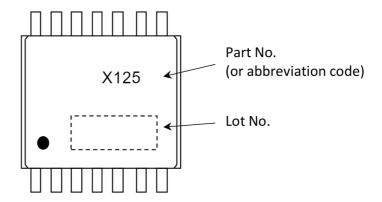
Start of commercial production



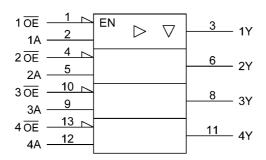
# 5. Pin Assignment



# 6. Marking



# 7. IEC Logic Symbol





#### 8. Truth Table

Inputs OE	Inputs A	Outputs Y
Н	Х	Z
L	L	L
L	Н	Н

X: Don't care

Z: High impedance

#### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 4.6	V
Input voltage	V <sub>IN</sub>		-0.5 to 4.6	V
Output voltage	V <sub>out</sub>	(Note 1)	-0.5 to 4.6	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-50	mA
Output diode current	I <sub>OK</sub>	(Note 3)	±50	mA
Output current	I <sub>OUT</sub>		±50	mA
Power dissipation	$P_D$		180	mW
V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>		±100	mA
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 



# 10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		1.2 to 3.6	V
Input voltage	V <sub>IN</sub>		-0.3 to 3.6	V
Output voltage	V <sub>OUT</sub>	(Note 1)	0 to 3.6	V
		(Note 2)	0 to V <sub>CC</sub>	
Output current	I <sub>OH</sub> ,I <sub>OL</sub>	(Note 3)	±24	mA
		(Note 4)	±18	
		(Note 5)	±6	
		(Note 6)	±2	
Operating temperature	T <sub>opr</sub>		-40 to 85	°C
Input rise and fall times	dt/dv	(Note 7)	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

Note 3:  $V_{CC}$  = 3.0 to 3.6 V

Note 4:  $V_{CC}$  = 2.3 to 2.7 V

Note 5:  $V_{CC}$  = 1.65 to 1.95 V

Note 6:  $V_{CC}$  = 1.4 to 1.6 V

Note 7:  $V_{IN}$  = 0.8 to 2.0 V ,  $V_{CC}$  = 3.0 V



#### 11. Electrical Characteristics

# 11.1. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.2 to 1.4	$V_{CC} \times 0.8$	_	V
				1.4 to 1.65	V <sub>CC</sub> × 0.65	_	
				1.65 to 2.3	$V_{CC} \times 0.65$	_	
				2.3 to 2.7	1.6	_	
				2.7 to 3.6	2.0	_	
Low-level input voltage	V <sub>IL</sub>	_		1.2 to 1.4	_	$V_{CC} \times 0.05$	V
				1.4 to 1.65	_	$V_{CC} \times 0.05$	
				1.65 to 2.3	_	V <sub>CC</sub> × 0.2	
				2.3 to 2.7	_	0.7	
				2.7 to 3.6	_	0.8	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.2	V <sub>CC</sub> - 0.1	_	V
				1.4 to 1.65	V <sub>CC</sub> - 0.2	_	
				1.65 to 3.6	V <sub>CC</sub> - 0.2	_	
			I <sub>OH</sub> = -2 mA	1.4	1.05	_	
			I <sub>OH</sub> = -6 mA	1.65	1.25	_	
				2.3	2.0	_	
			I <sub>OH</sub> = -12 mA	2.3	1.8	_	
				2.7	2.2	_	
			I <sub>OH</sub> = -18 mA	2.3	1.7	_	
				3.0	2.4	_	
			I <sub>OH</sub> = -24 mA	3.0	2.2	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.2	_	0.05	V
				1.4 to 1.65	_	0.05	
				1.65 to 3.6	_	0.2	
			I <sub>OL</sub> = 2 mA	1.4	_	0.35	
			I <sub>OL</sub> = 6 mA	1.65	_	0.3	
			I <sub>OL</sub> = 12 mA	2.3	_	0.4	
				2.7	_	0.4	
			I <sub>OL</sub> = 18 mA	2.3	_	0.6	
				3.0	_	0.4	
			I <sub>OL</sub> = 24 mA	3.0	_	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V	•	1.2 to 3.6	_	±5.0	μА
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.2 to 3.6	_	±10.0	μА
Power-OFF leakage current	I <sub>OFF</sub>	$V_{IN}/V_{OUT} = 0$ to 3.6 V		0		10.0	μΑ
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.2 to 3.6		20.0	μΑ
		$V_{CC} \le (V_{IN}/V_{OUT}) \le 3.6 \text{ V}$		1.2 to 3.6		±20.0	
	Δl <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per input)		2.7 to 3.6	_	750	μА



# 11.2. AC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		See 11.5 AC Test Circuit, Table 11.5.1, Fig. 11.6.1, Table 11.6.1	1.2	3.0	34.0	ns
				1.5 ± 0.1	2.0	13.6	
			Table 11.0.1	1.8 ± 0.15	1.5	6.8	
				$2.5 \pm 0.2$	0.8	3.4	
				$3.3\pm0.3$	0.6	2.8	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		See 11.5 AC Test Circuit,	1.2	3.0	41.0	ns
			Table 11.5.1, Fig. 11.6.2, Table 11.6.1	1.5 ± 0.1	2.0	16.4	
		Table 11.0.1	1.8 ± 0.15	1.5	8.2		
			2.5 ± 0.2	0.8	4.1		
				$3.3 \pm 0.3$	0.6	3.5	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		See 11.5 AC Test Circuit,	1.2	3.0	34.0	ns
			Table 11.5.1, Fig. 11.6.2, Table 11.6.1	1.5 ± 0.1	2.0	13.6	
			Table 11.0.1	1.8 ± 0.15	1.5	6.8	
				2.5 ± 0.2	0.8	3.8	
				3.3 ± 0.3	0.6	3.5	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	1.2	_	1.5	ns
				1.5 ± 0.1	_	1.5	]
			1.8 ± 0.15	_	0.5		
		2.5 ± 0.2	_	0.5			
				3.3 ± 0.3	_	0.5	

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

# 11.3. Dynamic Switching Characteristics (Note) (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	1.8	0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	2.5	0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	1.8	-0.25	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	2.5	-0.6	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	-0.8	
Quiet output minimum dynamic V <sub>OH</sub>	V <sub>OHV</sub>	V <sub>IH</sub> = 1.8 V, V <sub>IL</sub> = 0 V	1.8	1.5	V
		V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	2.5	1.9	
		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	2.2	

Note: Parameter guaranteed by design.

# 11.4. Capacitive Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>		_	1.8, 2.5, 3.3	6	pF
Output capacitance	C <sub>OUT</sub>		_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	f <sub>IN</sub> = 10 MHz	1.8, 2.5, 3.3	20	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC}(opr) = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per gate)

Rev.2.0



#### 11.5. AC Test Circuit

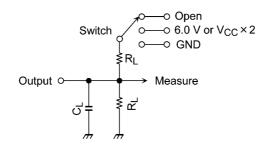


Table 11.5.1 Parameter for AC Test Circuit

Parameter	Switch	Test Condition
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN	_
t <sub>PLZ</sub> , t <sub>PZL</sub>	6.0 V	$V_{CC} = 3.3 \pm 0.3 \text{ V}$
	V <sub>CC</sub> × 2	$V_{CC} = 2.5 \pm 0.2 \text{ V}$
		V <sub>CC</sub> = 1.8 ± 0.15 V
		V <sub>CC</sub> = 1.5 ± 0.1 V
		V <sub>CC</sub> = 1.2 V
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND	_



#### 11.6. AC Waveform

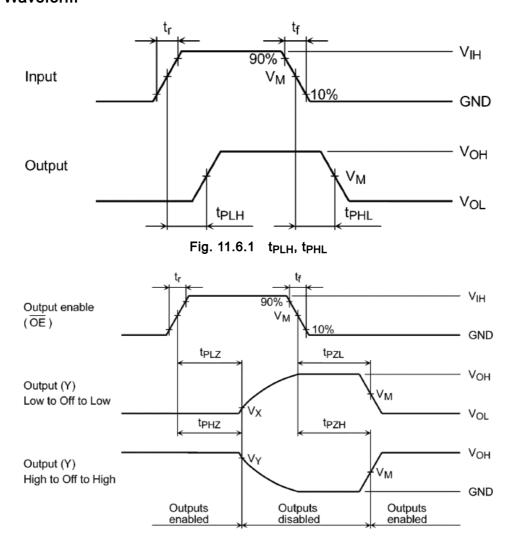


Fig. 11.6.2 t<sub>PLZ</sub>, t<sub>PHZ</sub>, t<sub>PZL</sub>, t<sub>PZH</sub>

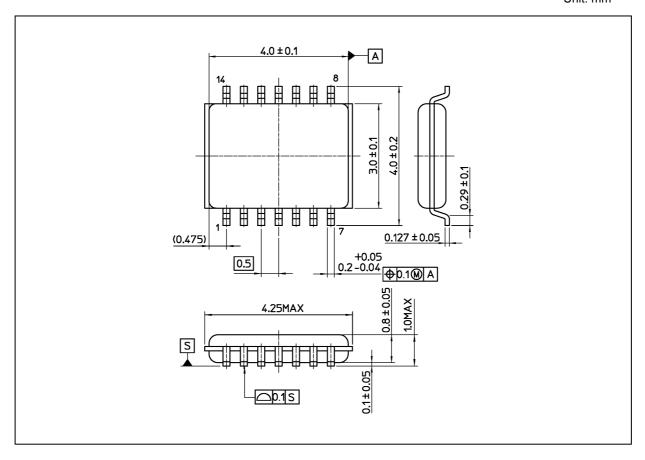
Table 11.6.1 AC Waveform Symbols

	Symbol	$V_{CC}$ = 3.3 ± 0.3 V	$V_{CC}$ = 2.5 ± 0.2 V $V_{CC}$ = 1.8 ± 0.15 V	$V_{CC} = 1.5 \pm 0.1 \text{ V}$ $V_{CC} = 1.2 \text{ V}$
Input	V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
	$V_{M}$	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	t <sub>r</sub> , t <sub>f</sub>	2.0 ns	2.0 ns	2.0 ns
Output	$V_{M}$	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
	V <sub>X</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.1 V
	$V_{Y}$	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.1 V
Load	C <sub>L</sub>	30 pF	30 pF	15 pF
	$R_L$	500 Ω	500 Ω	2 kΩ



# **Package Dimensions**

Unit: mm



Weight: 0.02 g (typ.)

	Package Name(s)
Nickname: US14	



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